

# Nanomaterials

## Lecture 10: Scanning Probe Lithography

# Atomic Force Microscopy Nanofabrication

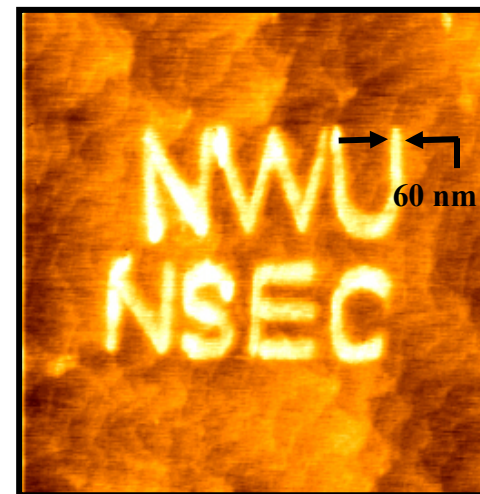
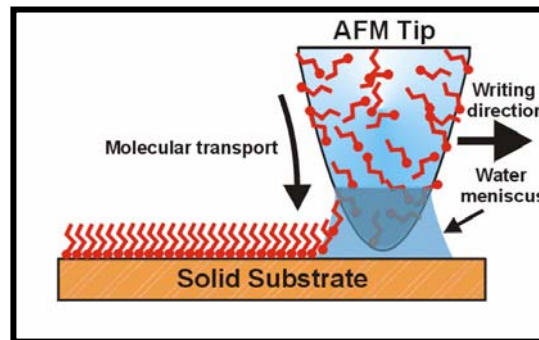
Many nanofabrication schemes have been developed with AFM (generally, spatial resolution is approximately 10 nm):

(1) Dip-pen nanolithography

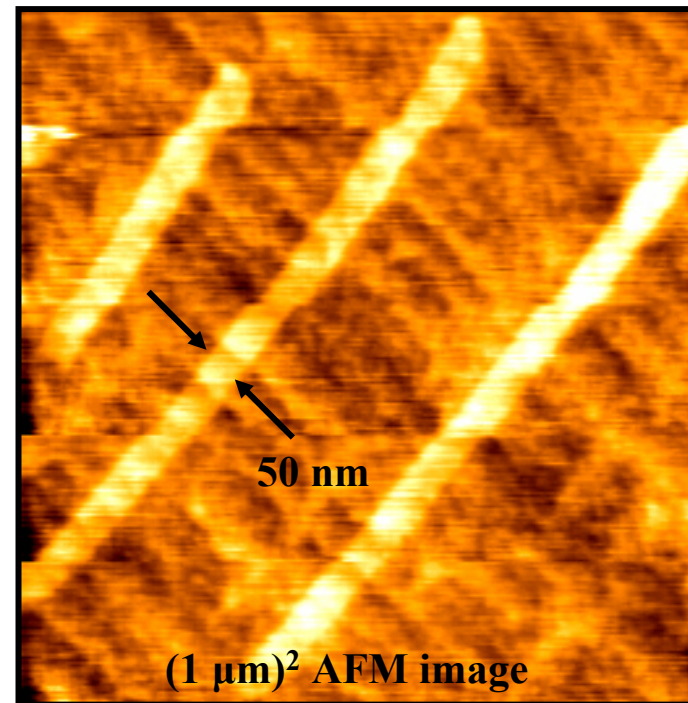
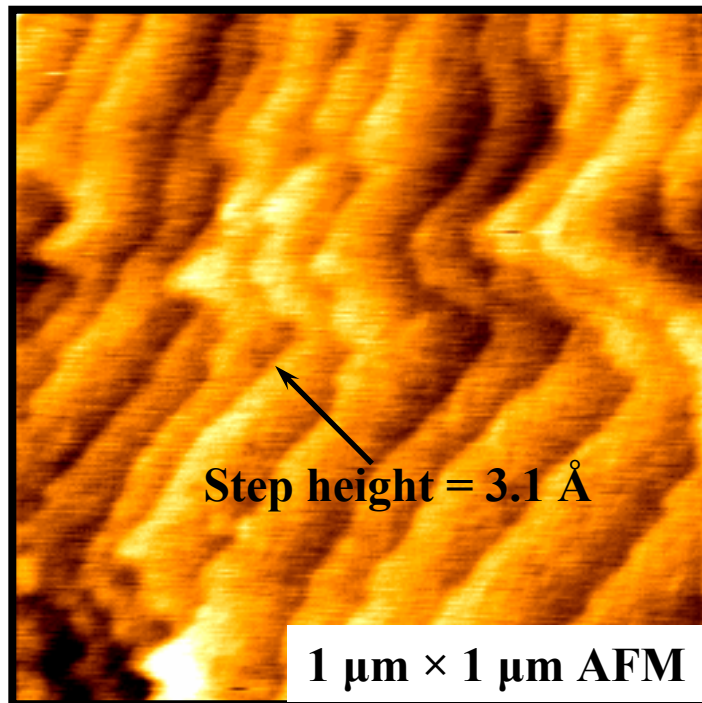
(2) Scratching, pushing

(3) Electrochemistry

(4) Tip-induced oxidation

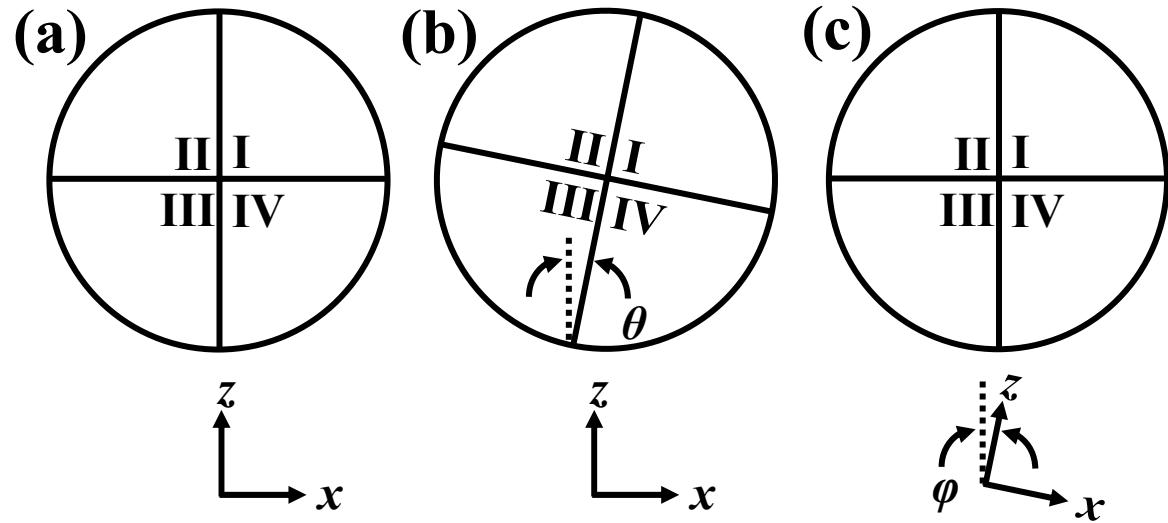
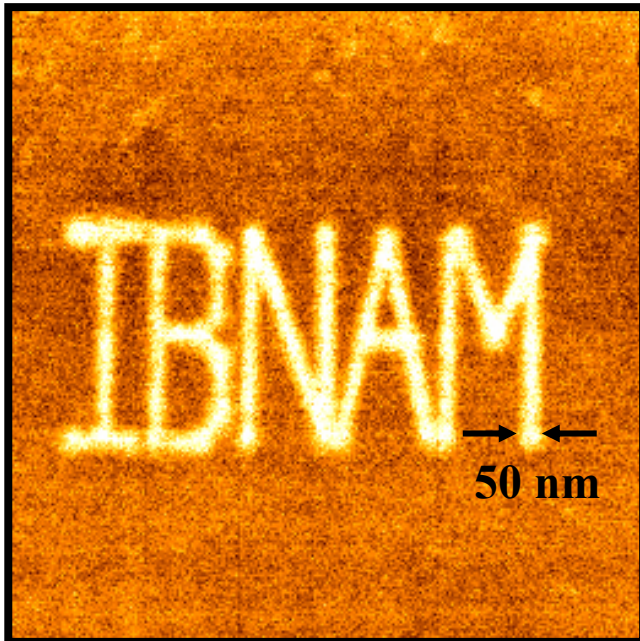


# Nano Oxidation of Silicon with Conductive AFM



- Oxide nanopatterns achieved via local anodization of Si(111):H
- Spatial resolution limited to ~10 nm.

# Lateral Force Microscopy

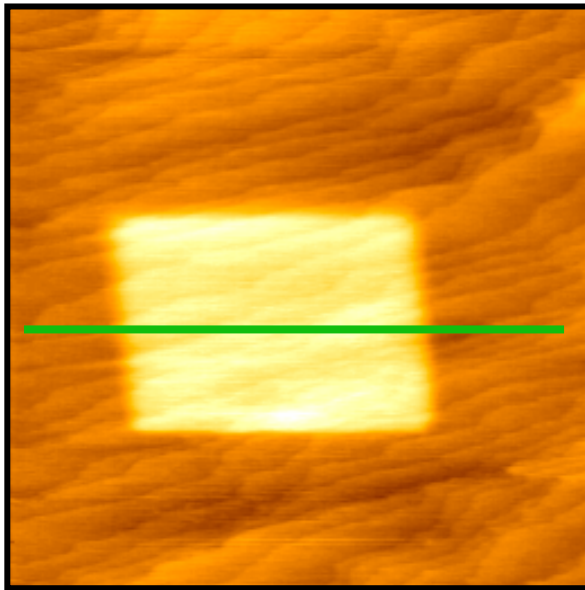


- Chemical contrast monitored via frictional force.
- Care must be taken to extract quantitative LFM data.

M. W. Such, D. E. Kramer & M. C. Hersam, *Ultramicroscopy*, **99**, 189 (2004).

# Selective Polymerization Chemistry

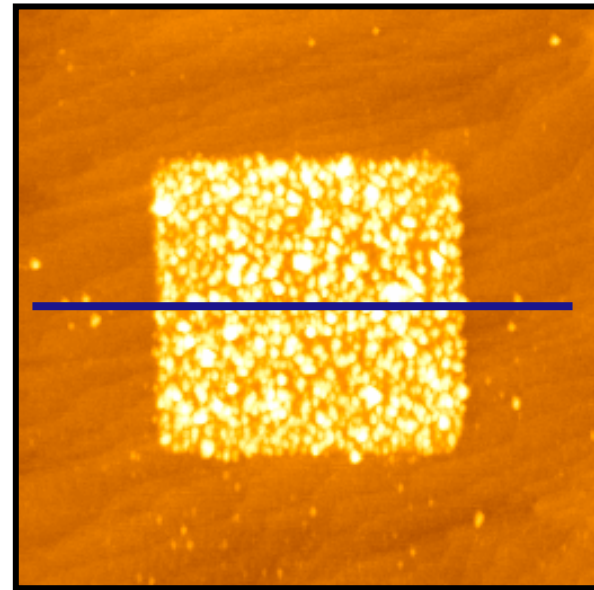
Before ROMP: 1  $\mu\text{m}$  FIO



2  $\mu\text{m}$  x 2  $\mu\text{m}$

7 V  
Sample  
Bias

After ROMP: 1  $\mu\text{m}$  FIO



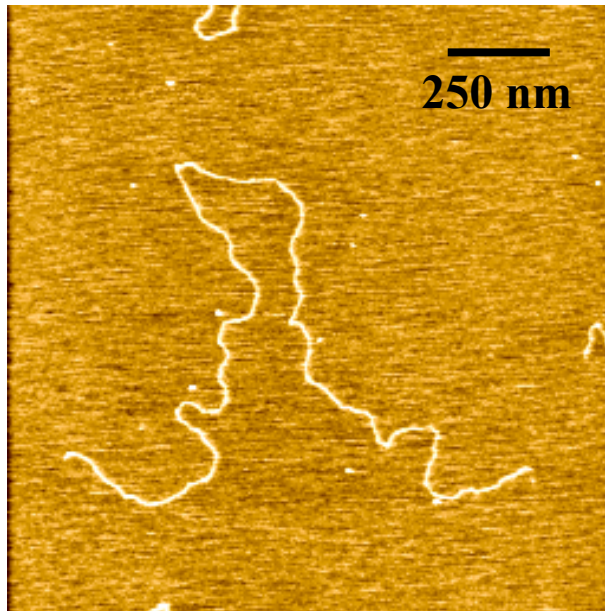
2  $\mu\text{m}$  x 2  $\mu\text{m}$

**ROMP = Ring Opening Metathesis Polymerization**

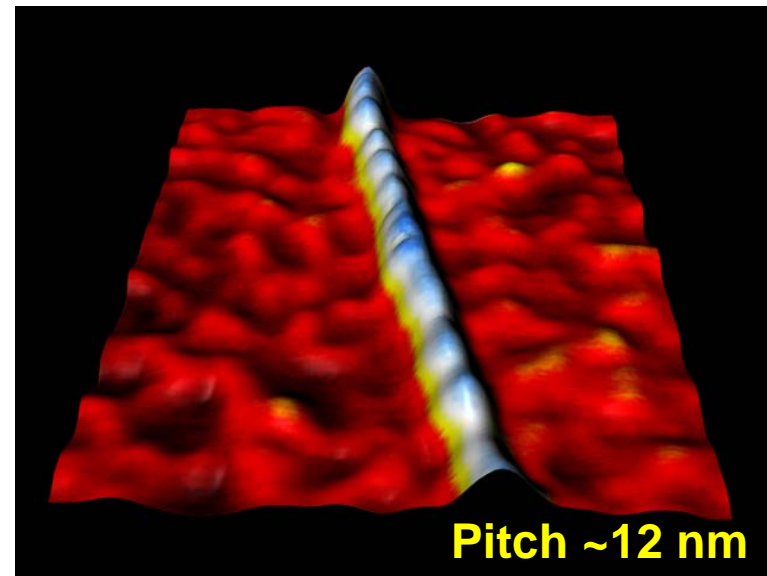
**Collaboration with SonBinh Nguyen**

# “Single Molecule Imaging” with Ambient AFM

**DNA Molecules**



**DNA Wrapped SWNTs**



Typical ambient AFM resolution is ~10 nm as opposed to atomic resolution for STM → STM is typically the technique of choice for intramolecular spatial resolution imaging

## Example Ultra-high Vacuum (UHV) STM Design



- Homebuilt STM in the Hersam lab at Northwestern University
- STM is a modified Lyding scanner

## Scanner Construction: Piezotubes

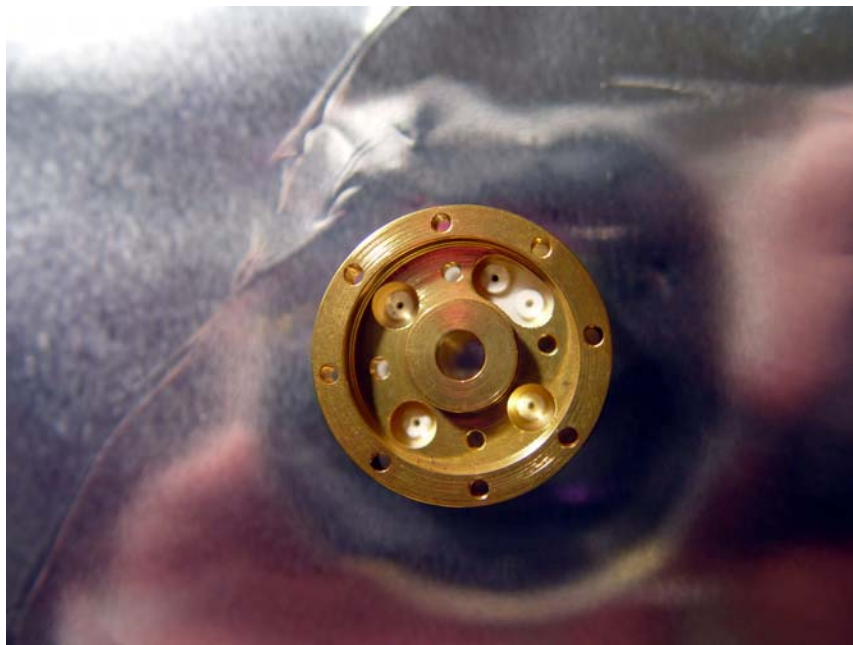
Outer tube:  
0.650" OD  
0.570" ID  
0.750" Long



Inner tube:  
0.375" OD  
0.315" ID  
0.750" Long



## Scanner Construction: Base Plug



Front View



Rear View

# Scanner Construction: Piezotubes Soldered into Base Plug



# Scanner Construction: Course Translation Platform



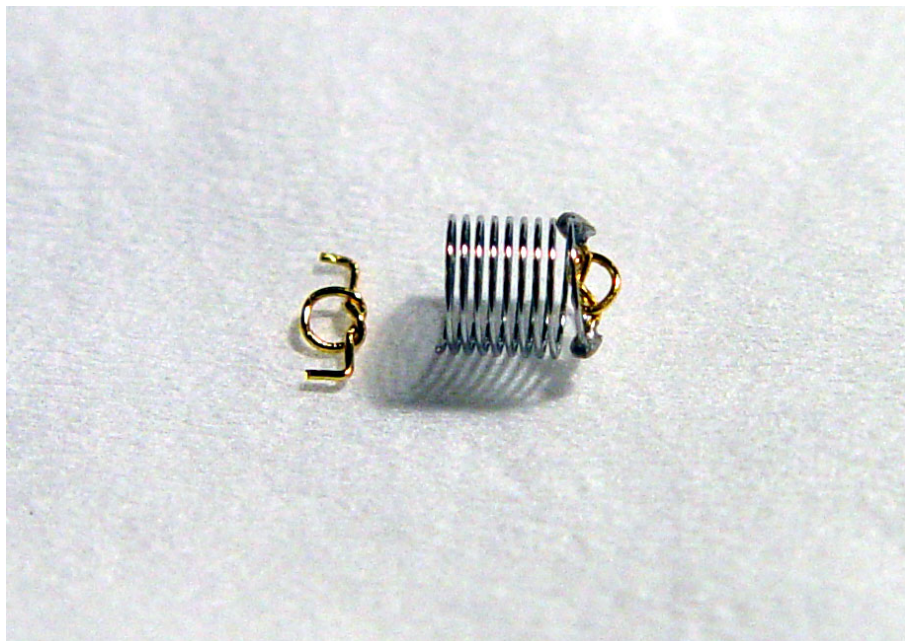
# Scanner Construction: Course Translation Platform Soldered onto Outer Piezotube



# Scanner Construction: End Cap Positioned onto Inner Piezotube



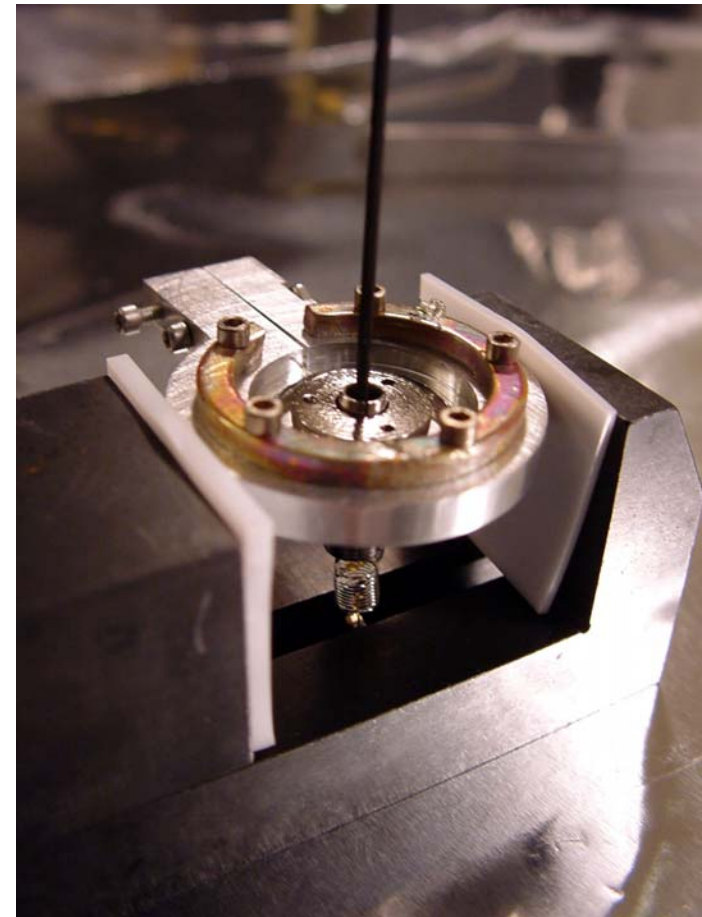
## Scanner Construction: Tip Contact Assembly



# Scanner Construction: Full Tip Assembly

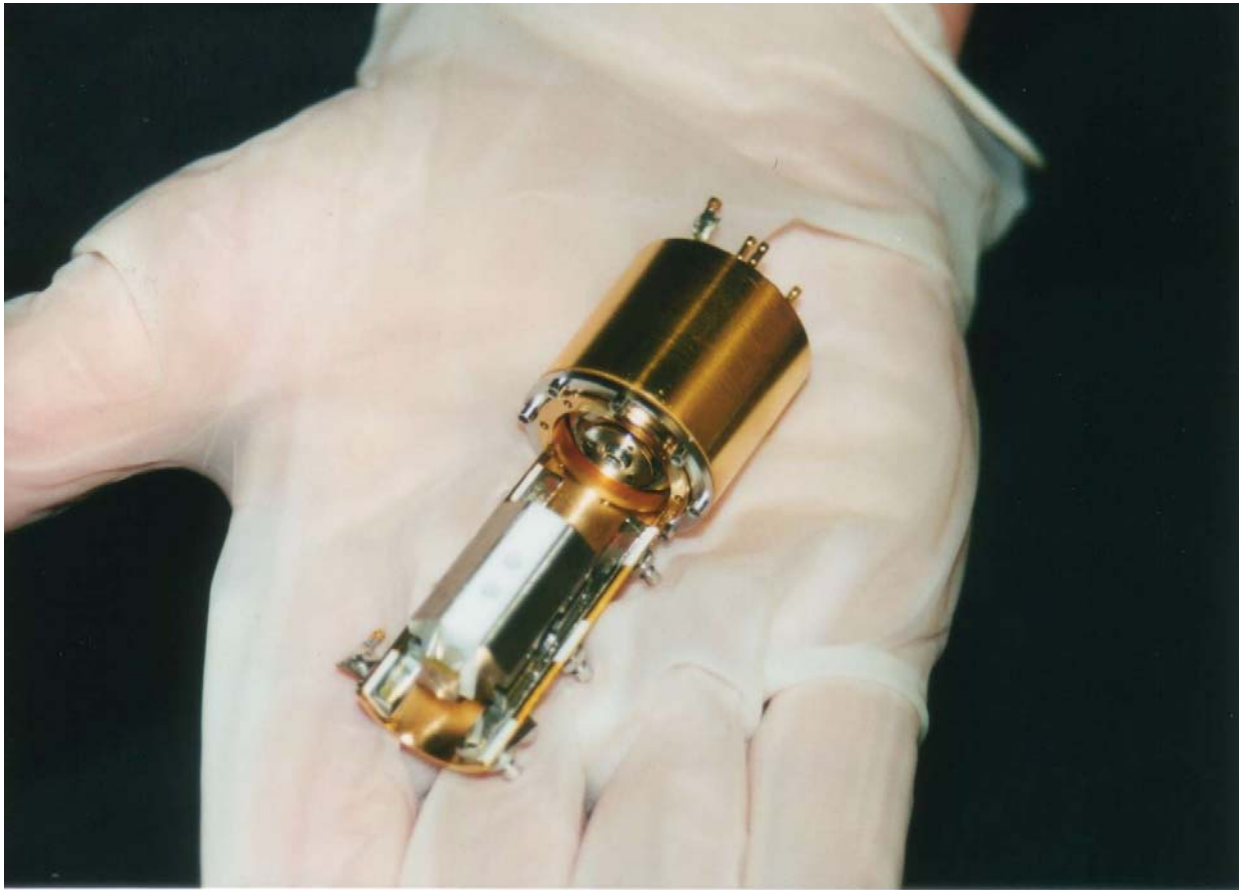


**Scanner Construction:  
Adjusting Clamping Force  
on Sapphire Washer and  
Soldering into Inner  
Piezotube End Cap**

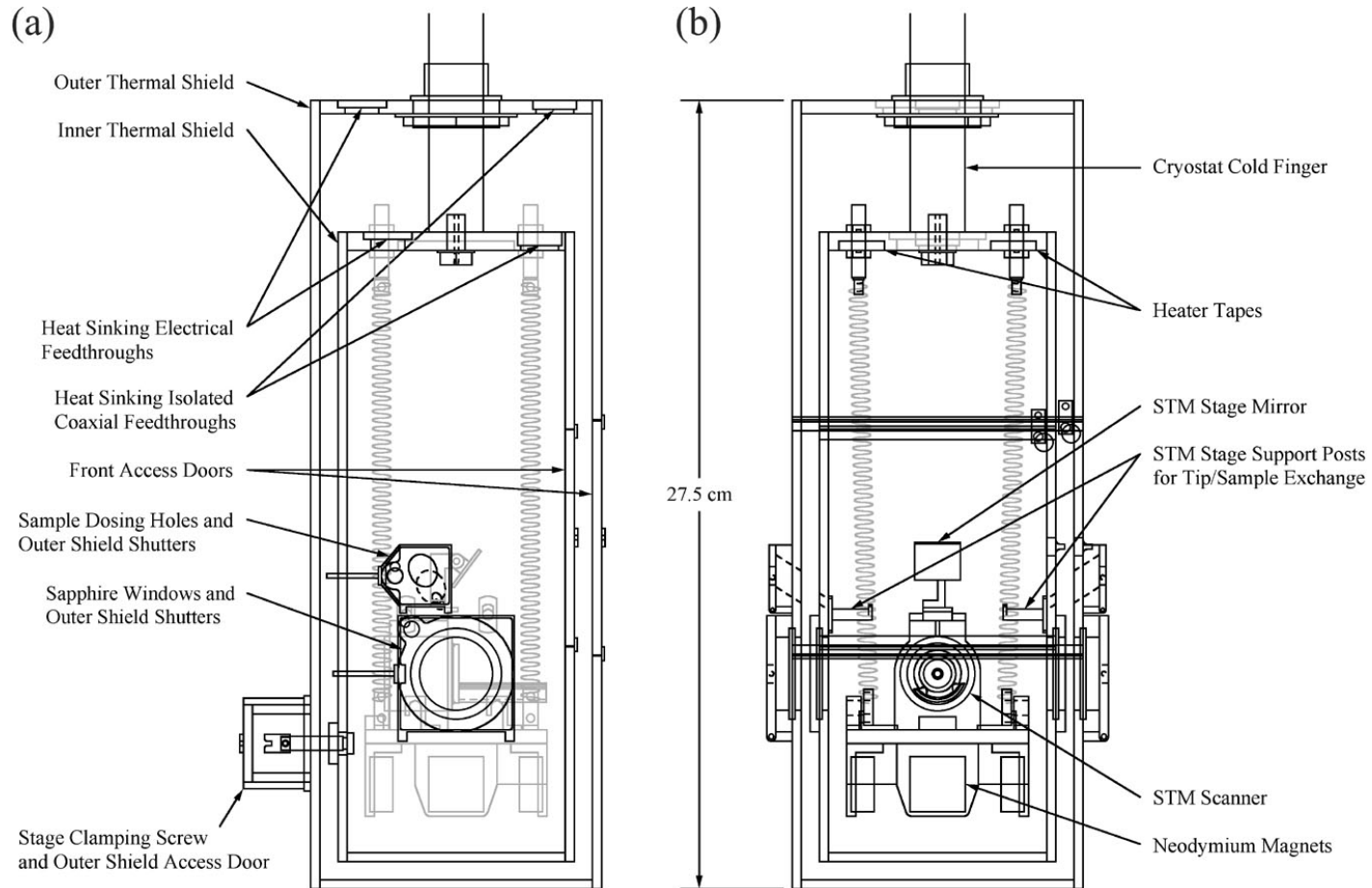




# Scanner Complete



# Cryogenic Variable Temperature UHV STM

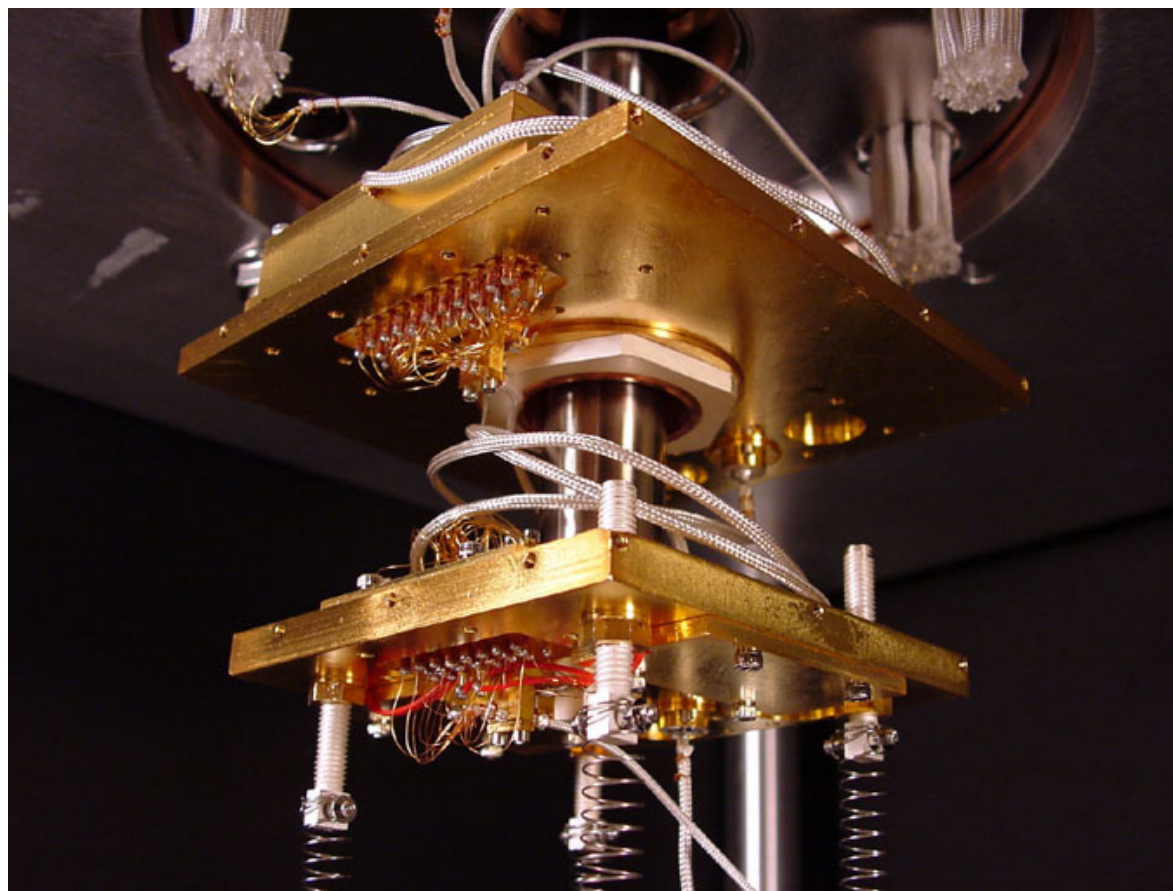


E. T. Foley, *et al.*, *Rev. Sci. Instrum.*, **75**, 5280 (2004).

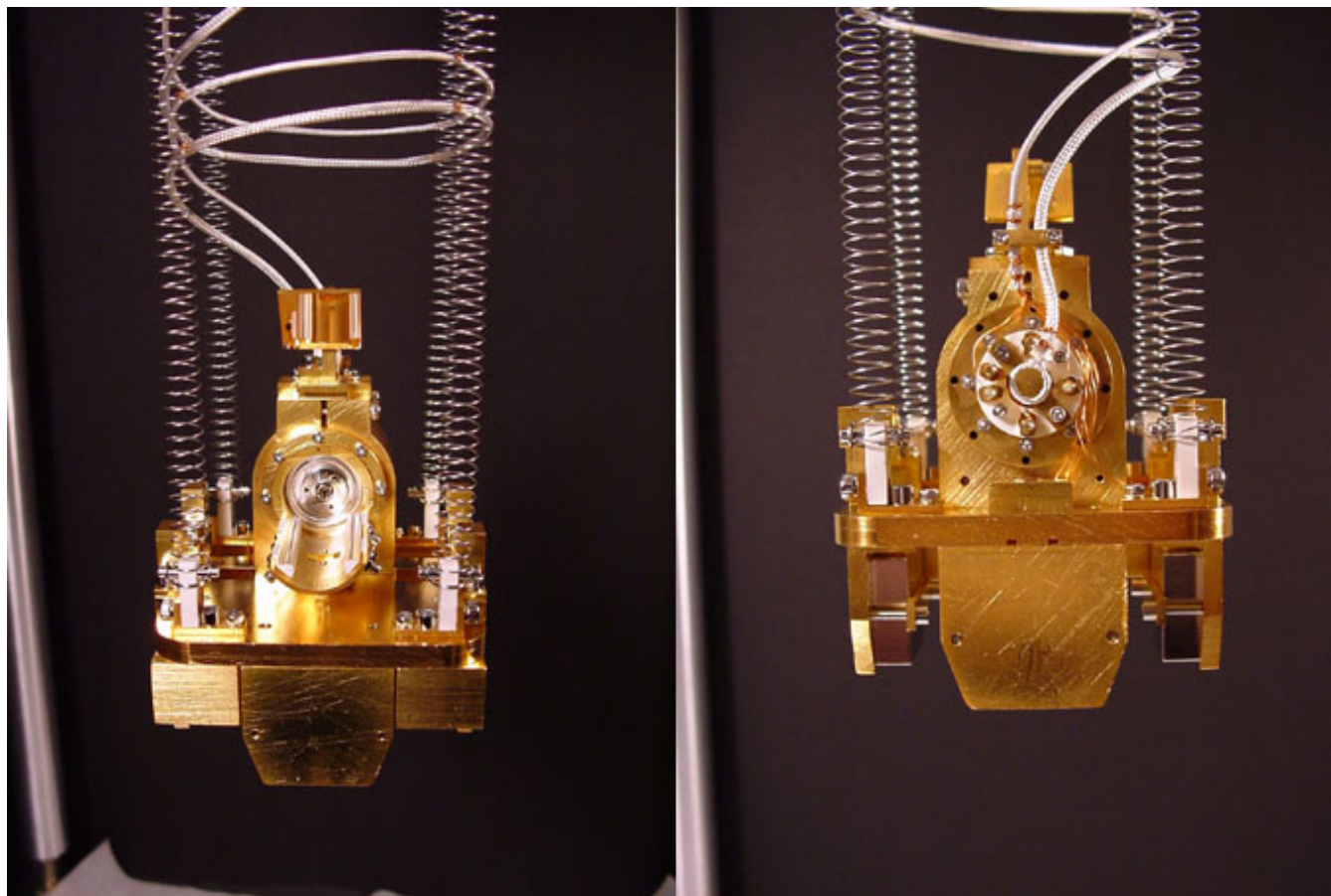
# Vibration Isolation



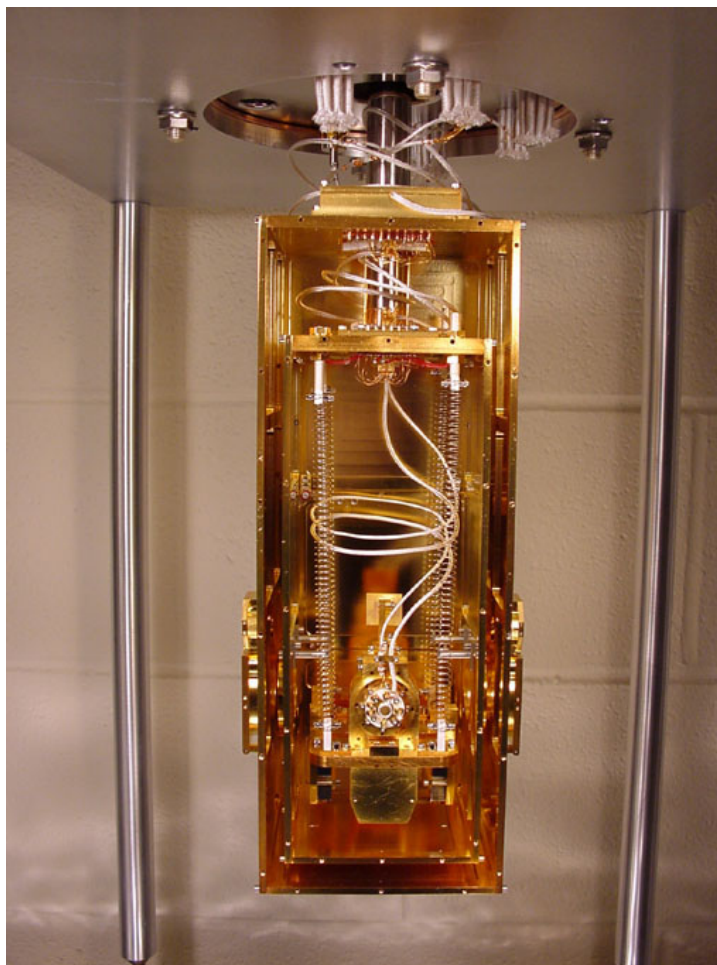
## Detail of Roof Plate



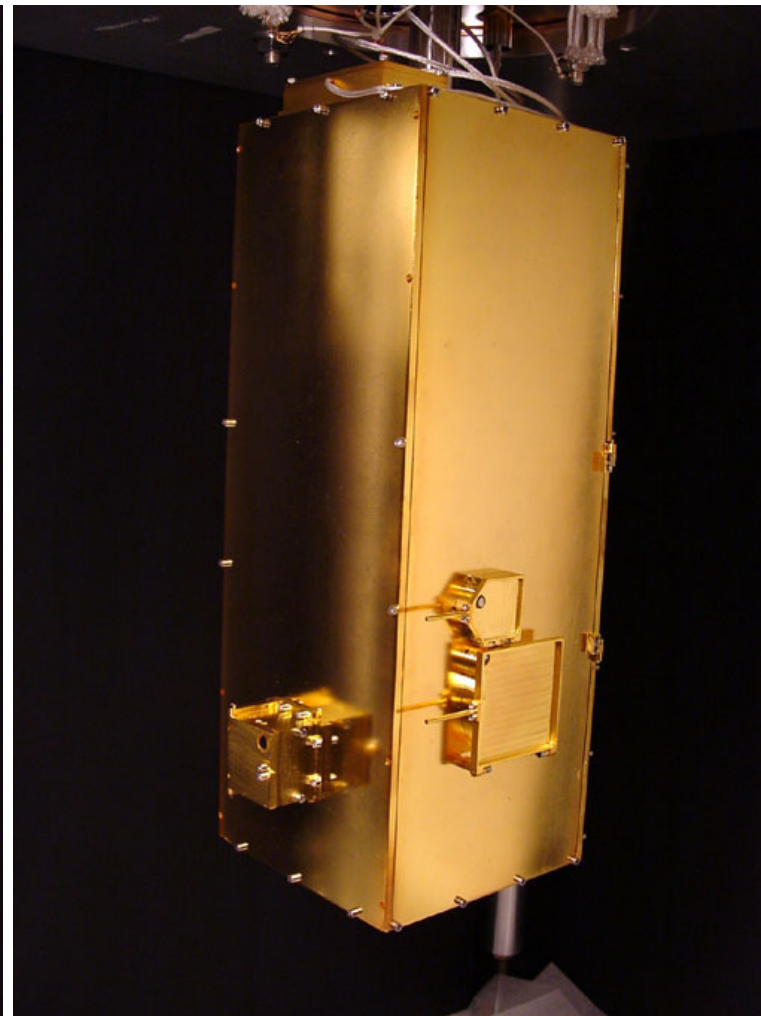
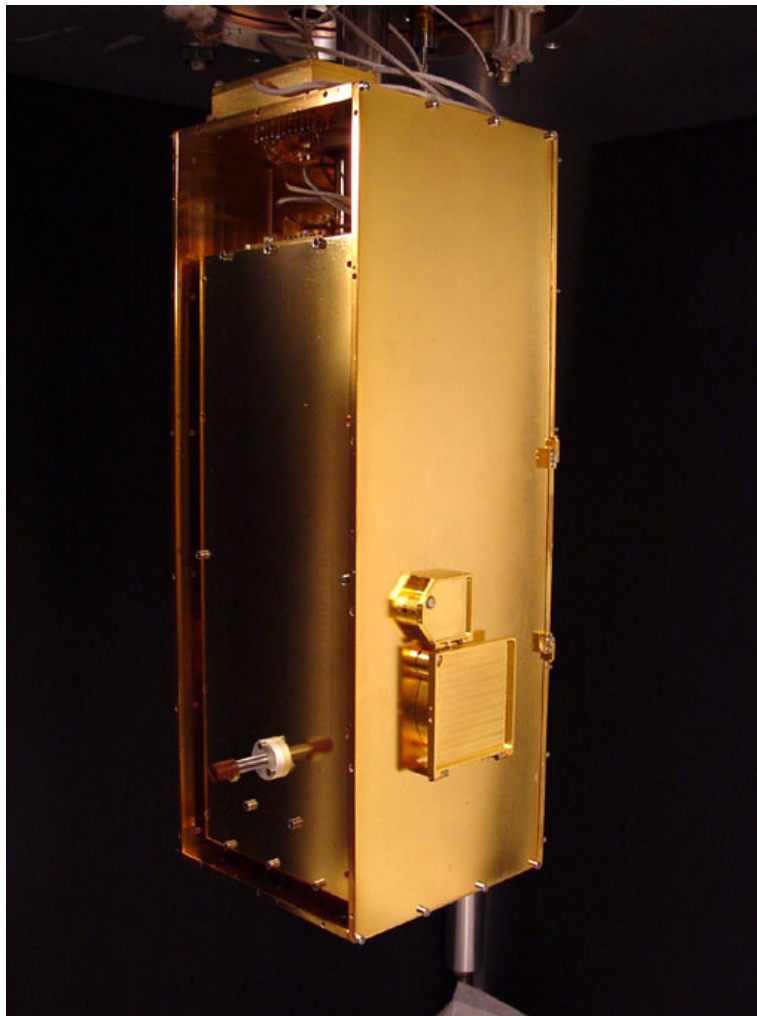
## Detail of STM Stage



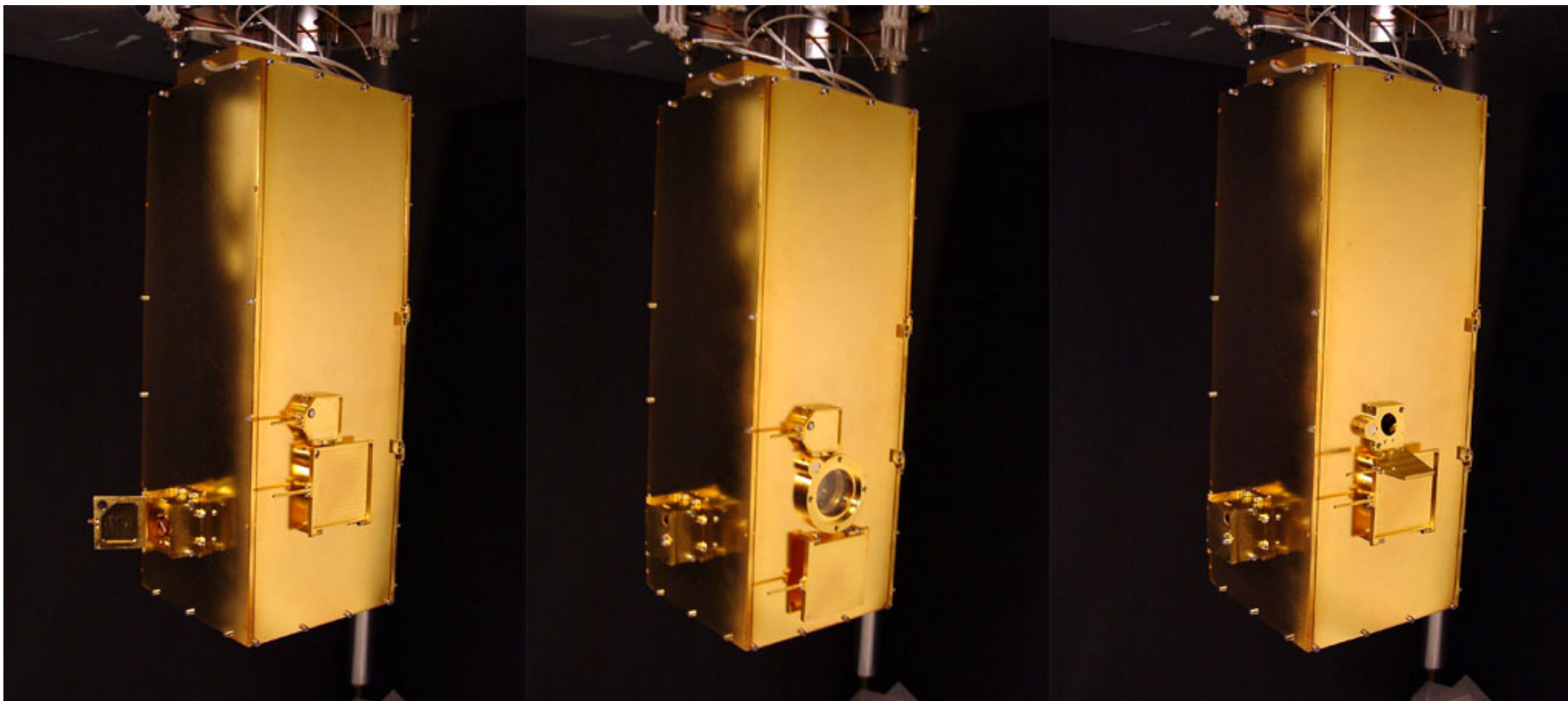
# Thermal Shields with Back Panel Removed



# Stage Locking Screw for Cooldown

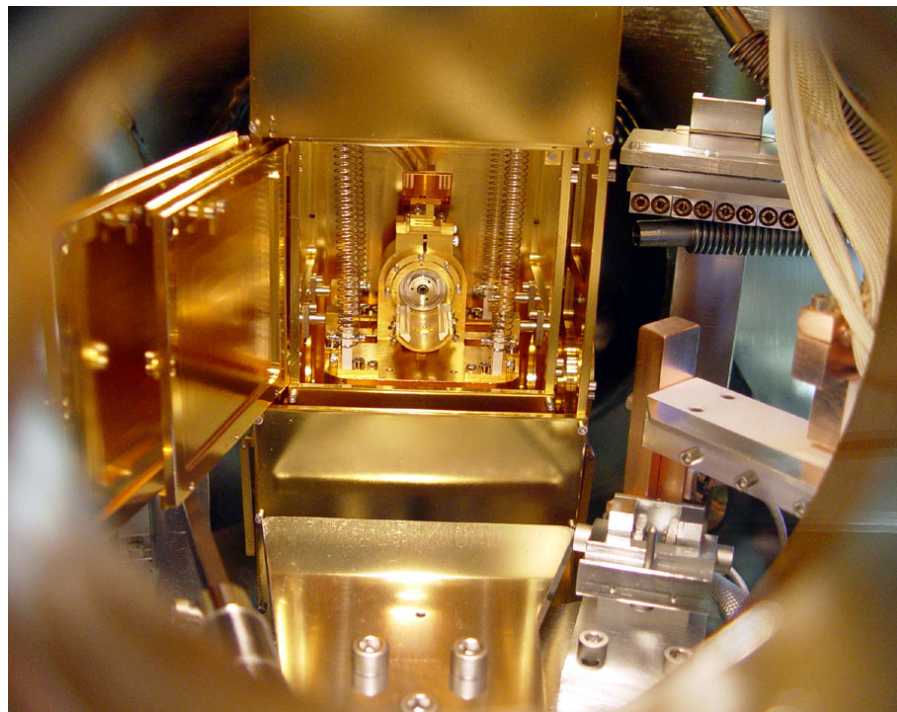


## Rear Door and Shutter Action

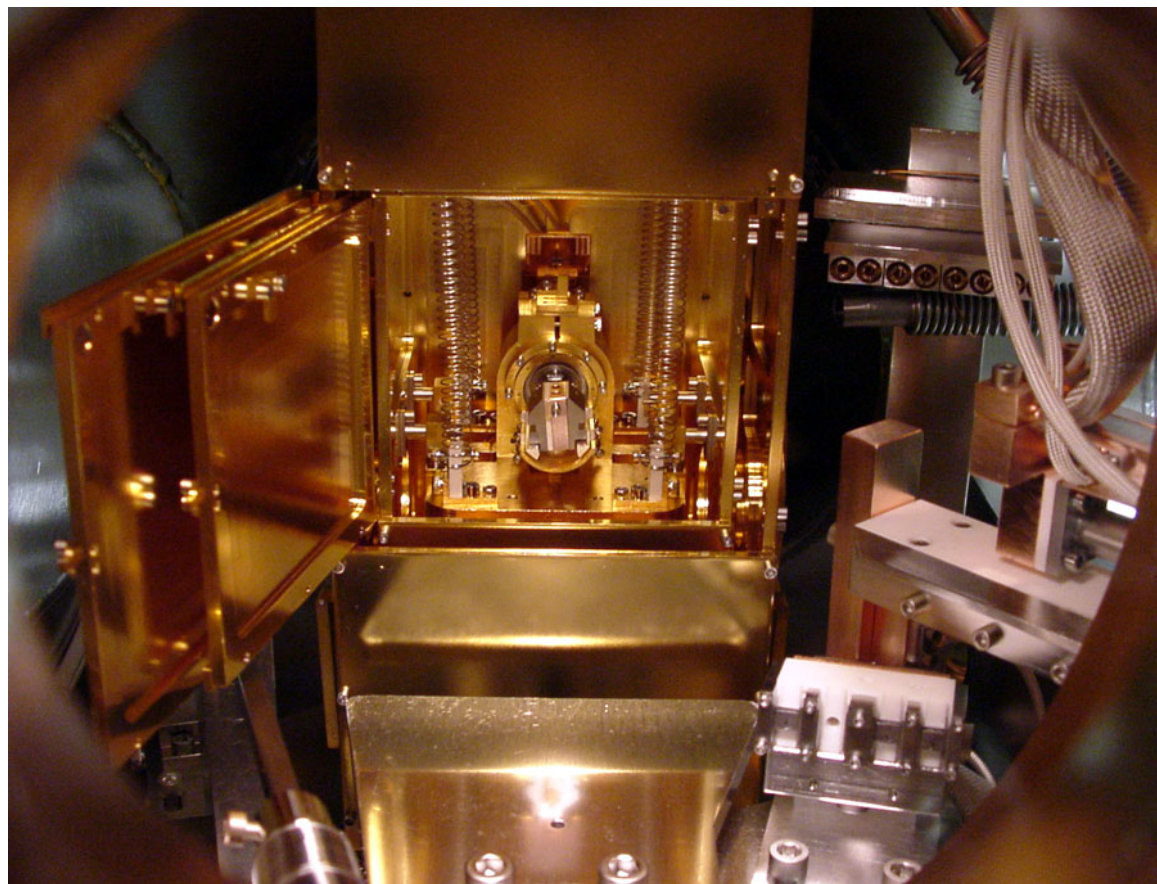




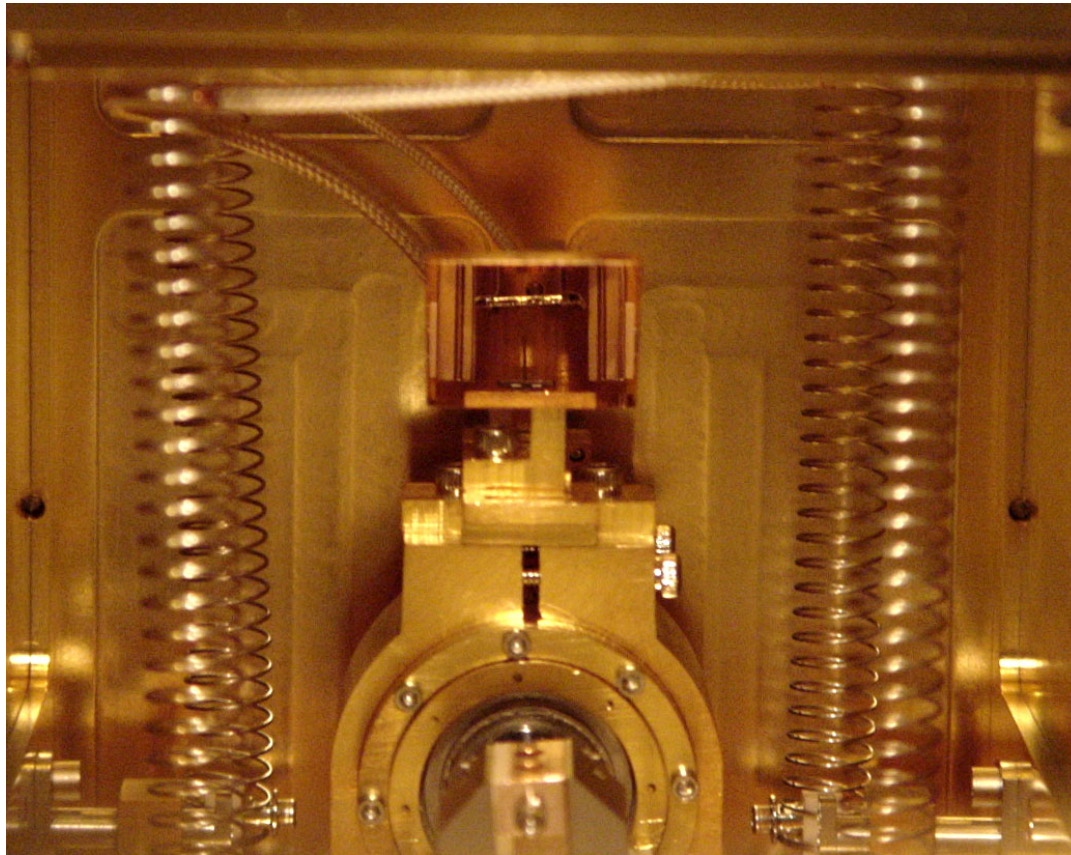
# Front Doors Open for STM Access



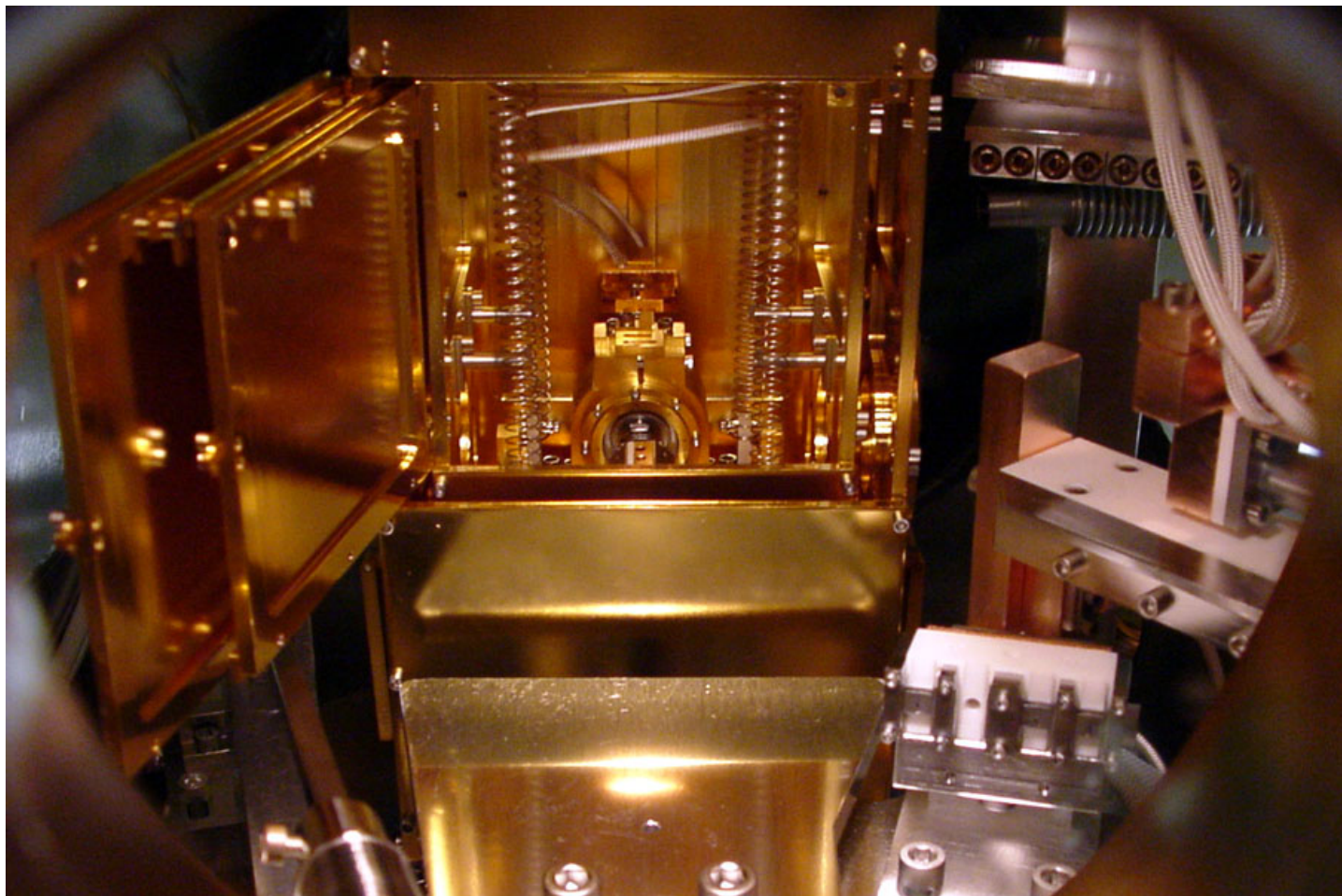
# Sample and Probe Mounted for Scanning



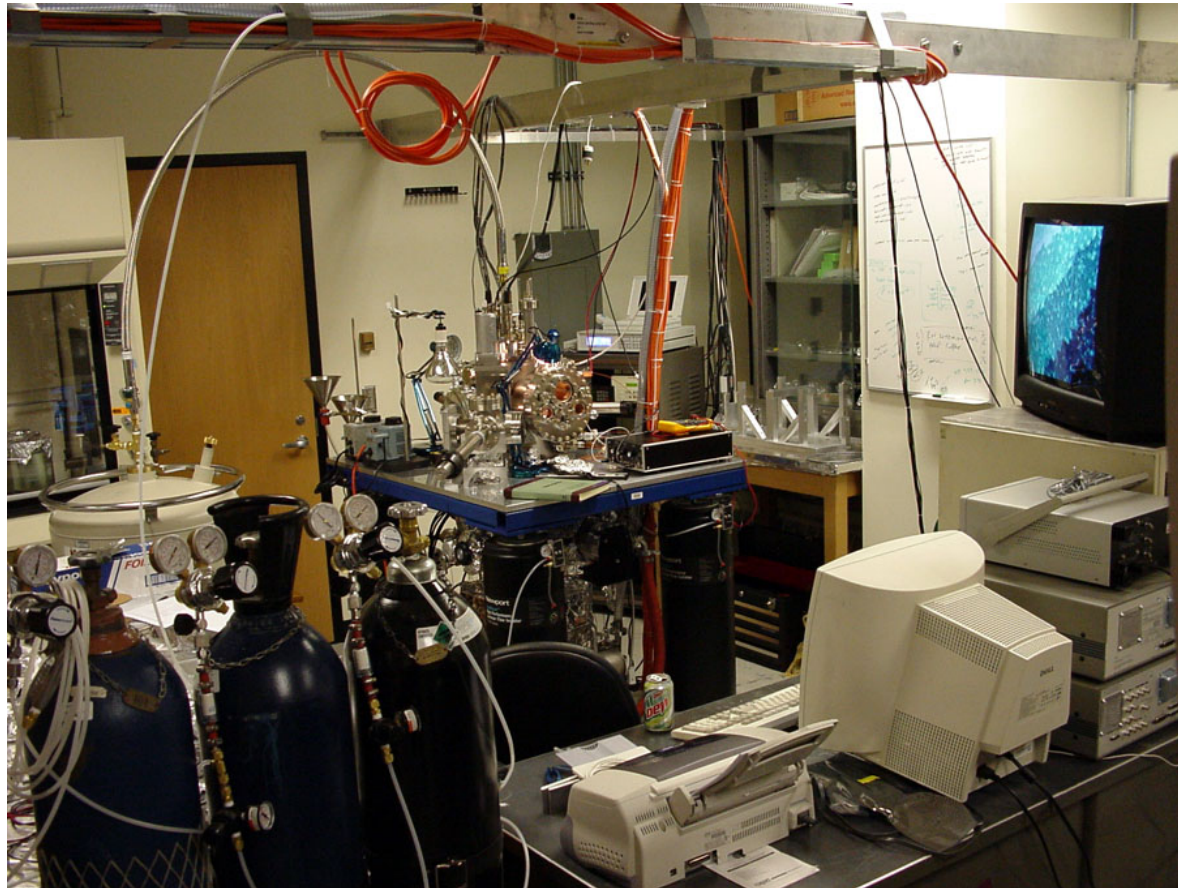
# Mirror Allows for Top-Down View of Tip-Sample Junction



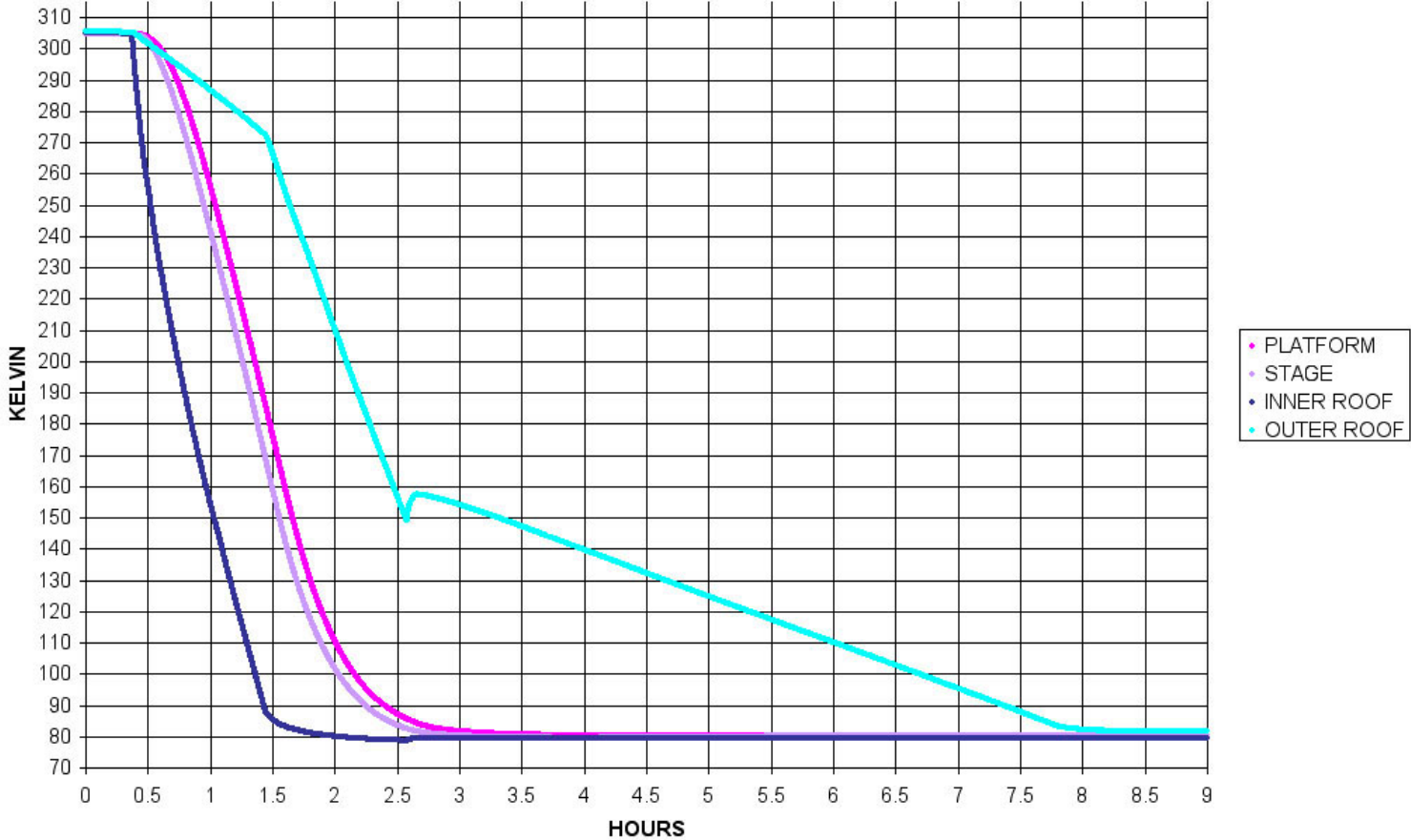
# STM Suspended for Scanning



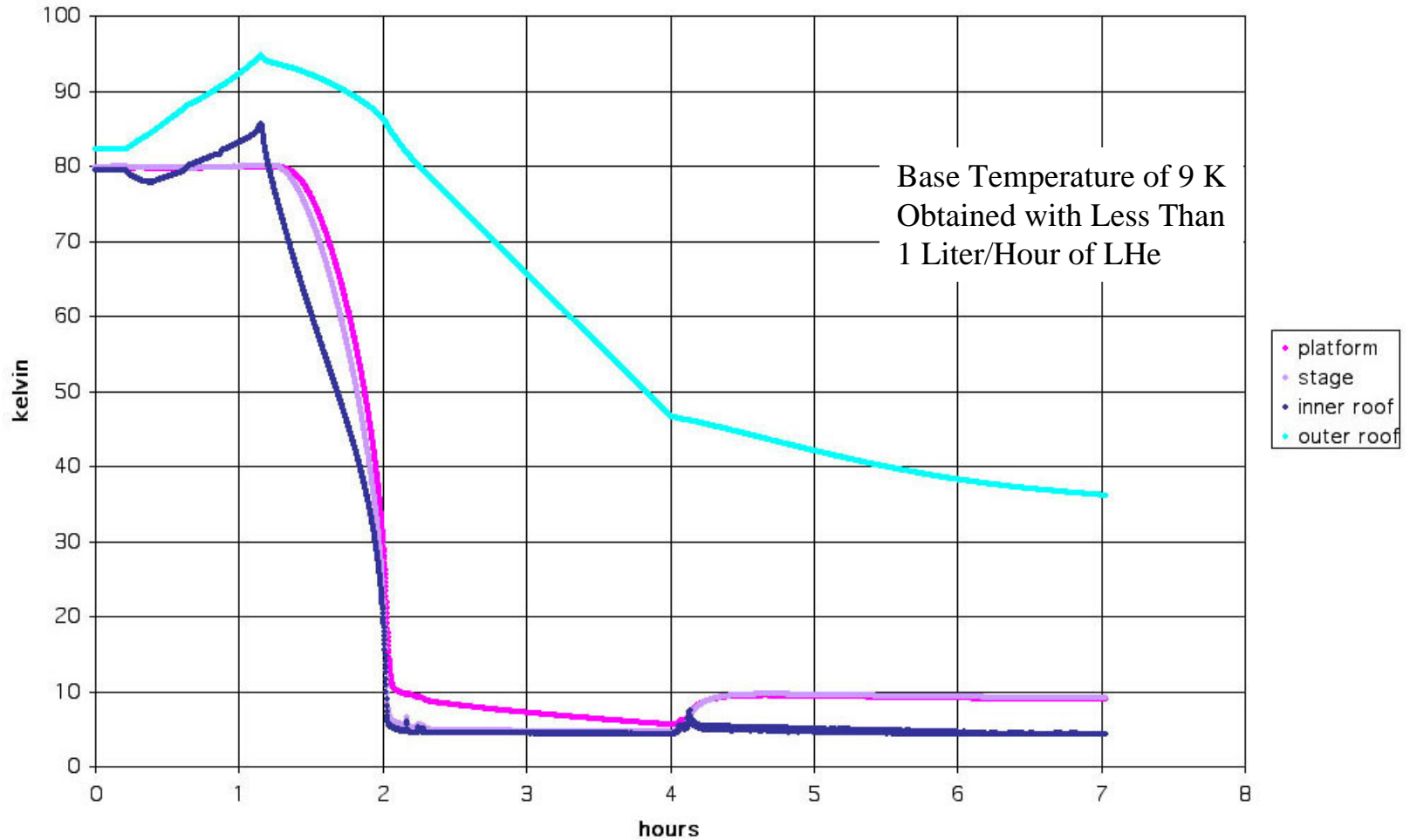
# UHV Chamber and Liquid Helium Dewar



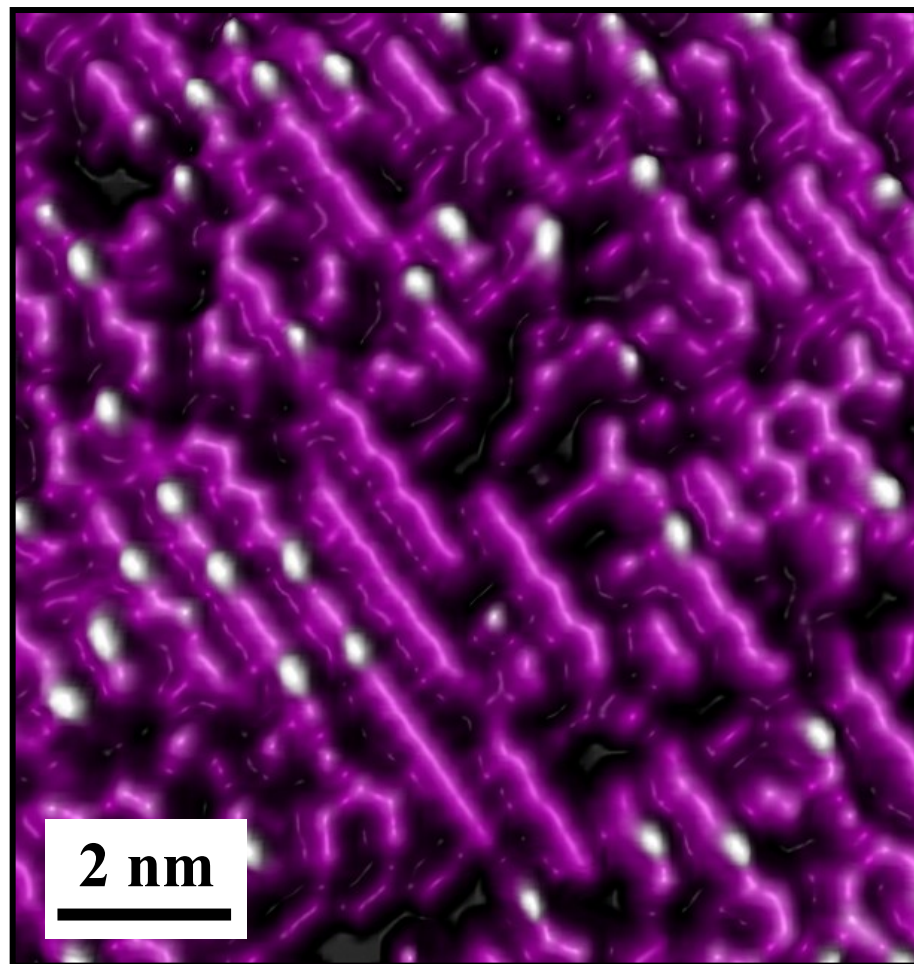
# Cooling with Liquid Nitrogen



# Cooling with Liquid Helium

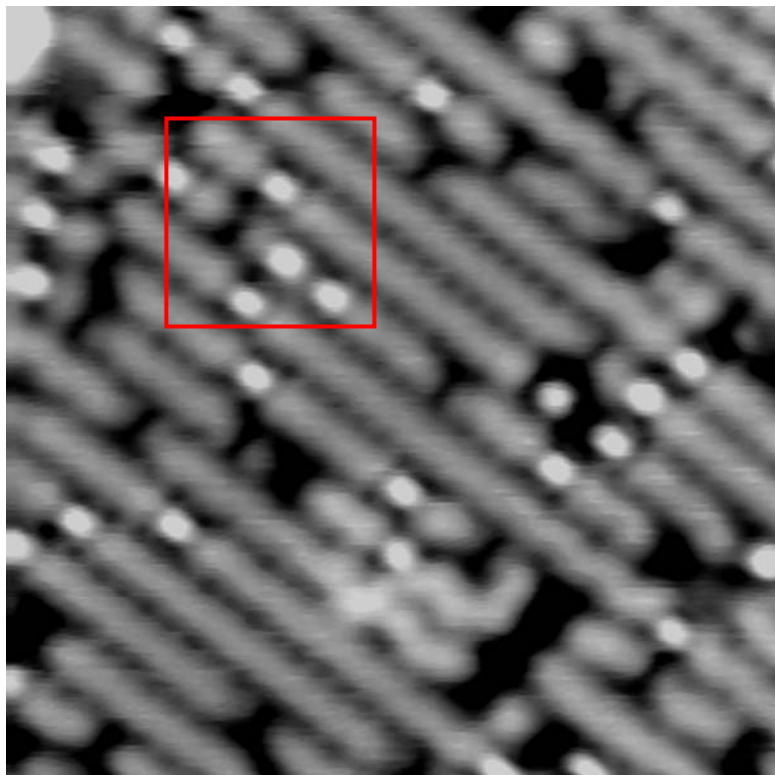


# Si(100) Dosed with Cyclopentene at 80 K

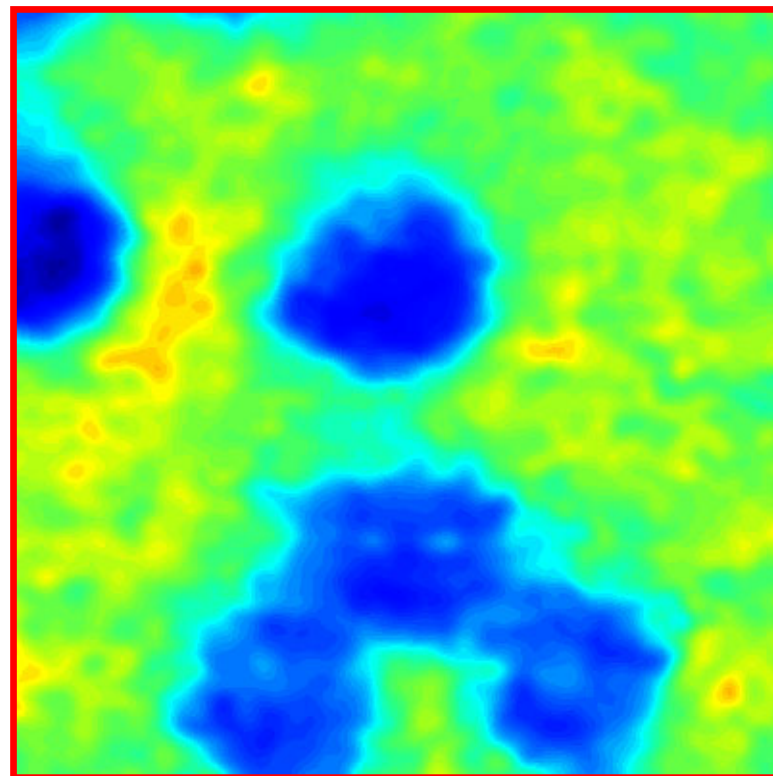




# dI/dV Imaging of Cyclopentene on Si(100) at 80 K

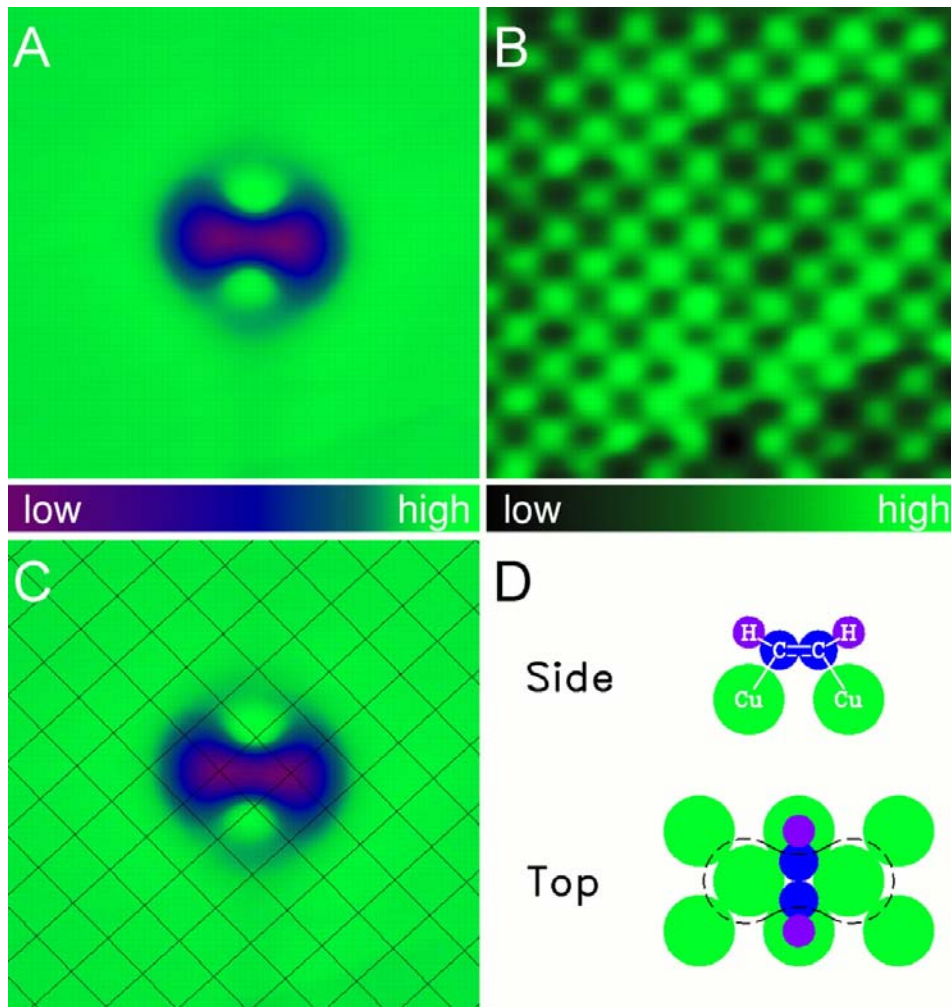


150 Å x 150 Å, -2.15 V, 0.1 nA



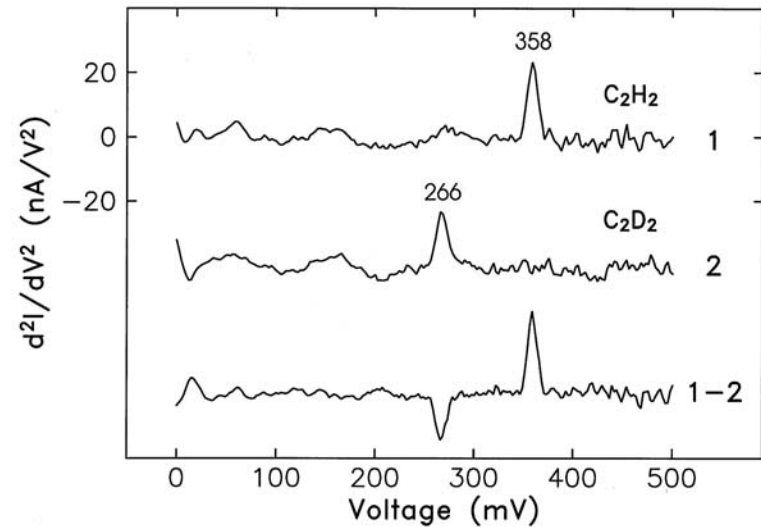
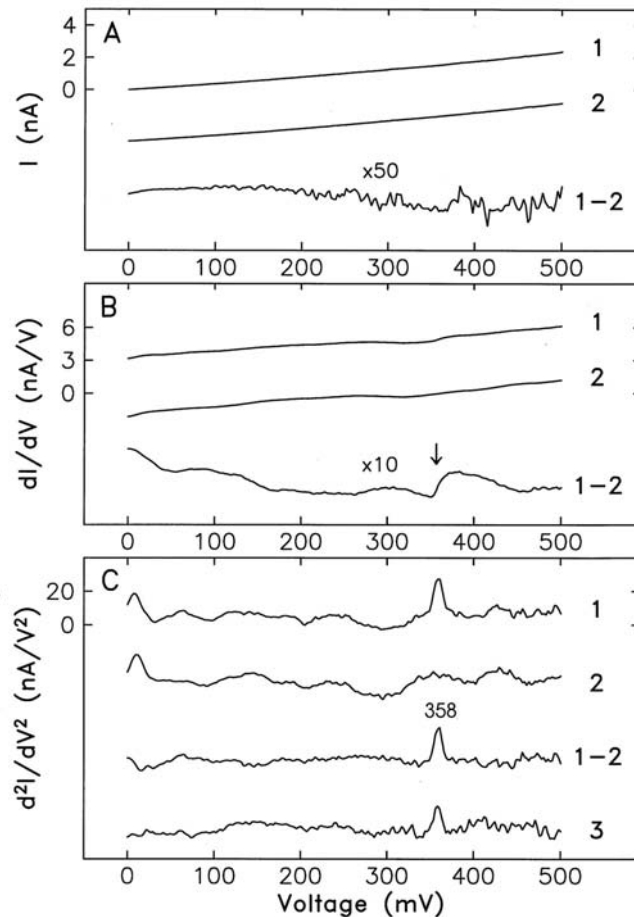
dI/dV Map at -2.8 V

# $C_2H_2$ on Cu(100)



B. C. Stipe, *et al.*,  
*Science*, **280**, 1732 (1998).

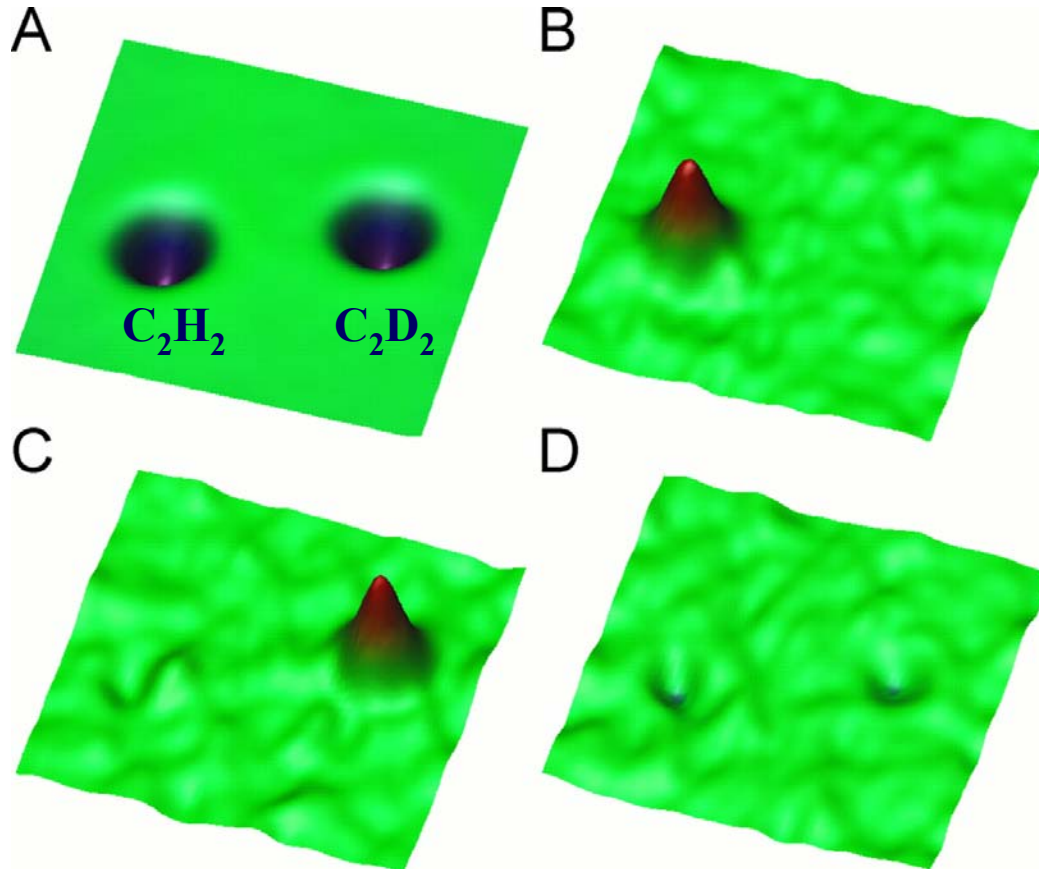
# Inelastic Electron Tunneling Spectroscopy



B. C. Stipe, *et al.*,  
*Science*, **280**, 1732 (1998).

# Spatial Maps of $d^2I/dV^2$

Topo



$d^2I/dV^2$   
@ 358 mV

$d^2I/dV^2$   
@ 266 mV

$d^2I/dV^2$   
@ 311 mV

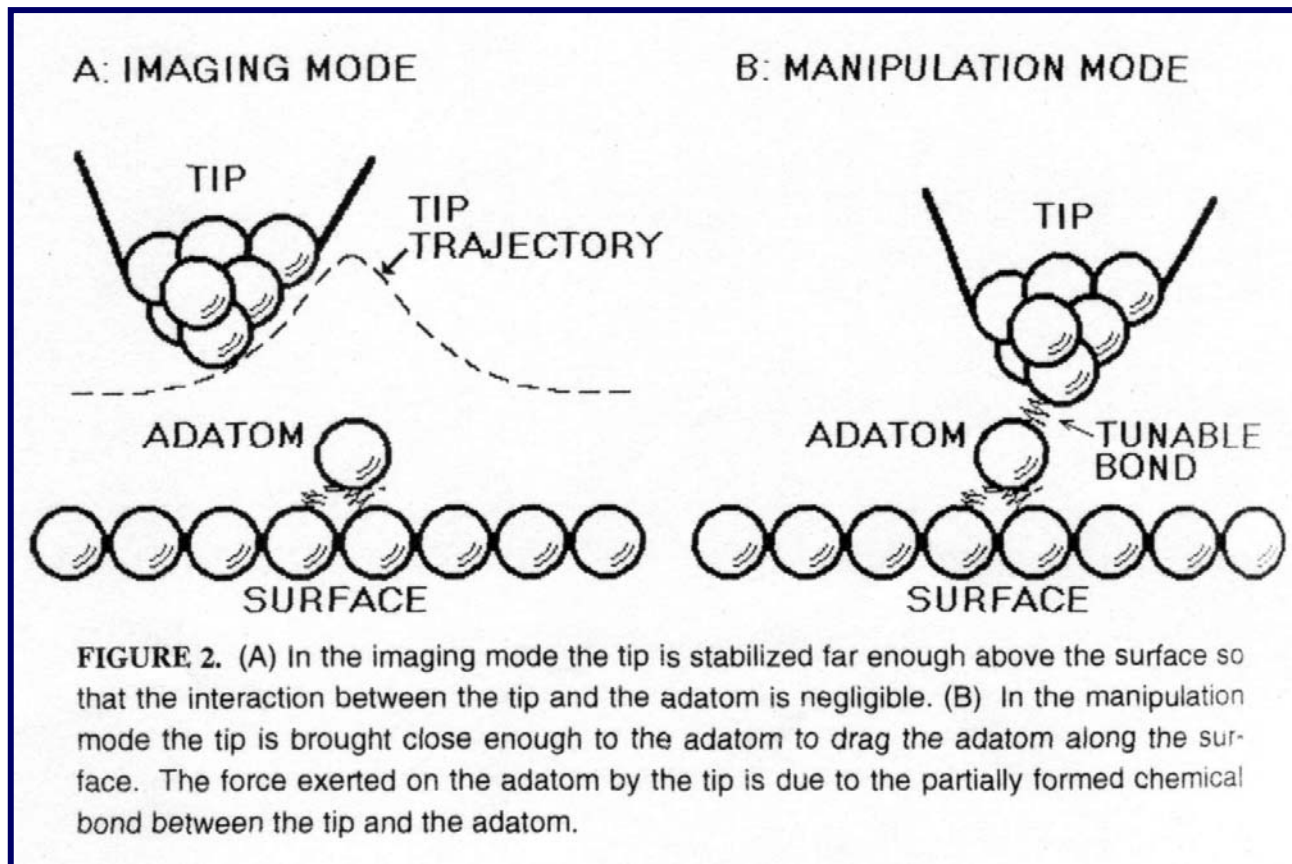
B. C. Stipe, *et al.*, *Science*, **280**, 1732 (1998).

# Scanning Tunneling Microscopy Nanofabrication

Many nanofabrication schemes have been developed with STM (spatial resolution down to the single atom level):

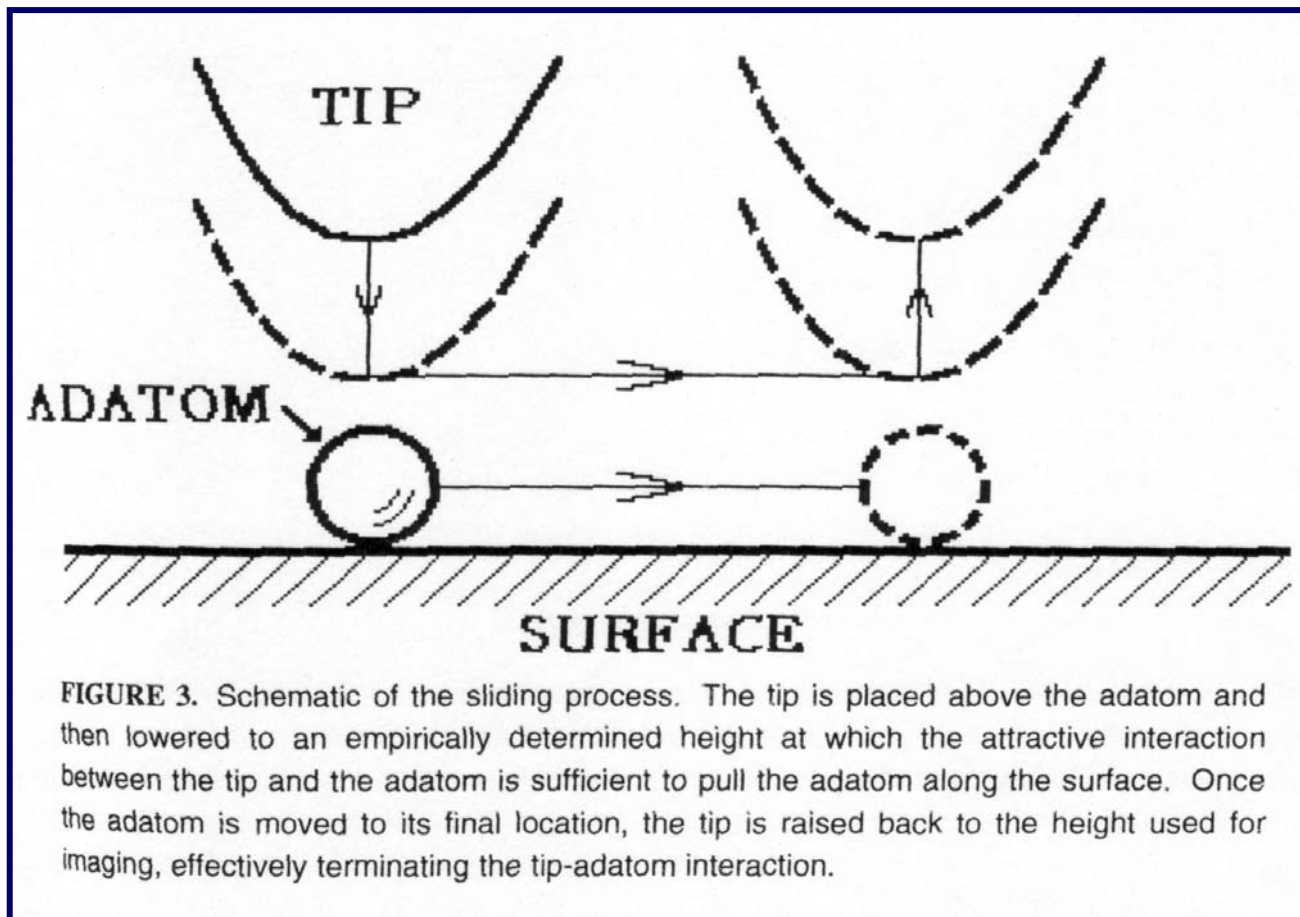
- (1) Initially demonstrated by Eigler in 1989  
("IBM" written with atoms at cryogenic temperatures)
- (2) Room temperature atom removal from Si(111) by Avouris
- (3) Field evaporation of gold
- (4) Electron stimulated desorption of hydrogen from Si(100)

# Tunable Bond Formation with STM



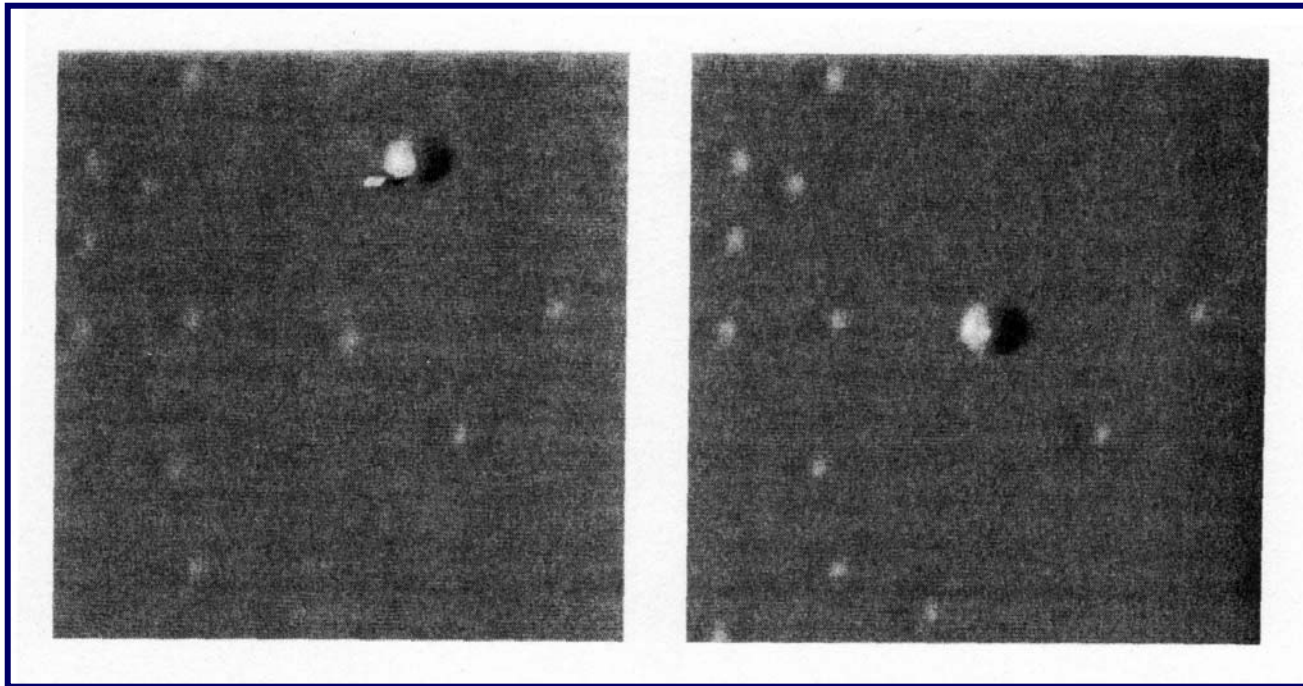
G. Timp, *Nanotechnology*, Chapter 11

# Sliding Adatoms with STM



G. Timp, *Nanotechnology*, Chapter 11

# The First Atom Moved with STM



Xenon on platinum → requires a defect to prevent tip-induced motion under normal scanning conditions

G. Timp, *Nanotechnology*, Chapter 11



# STM Manipulation of Xenon on Nickel

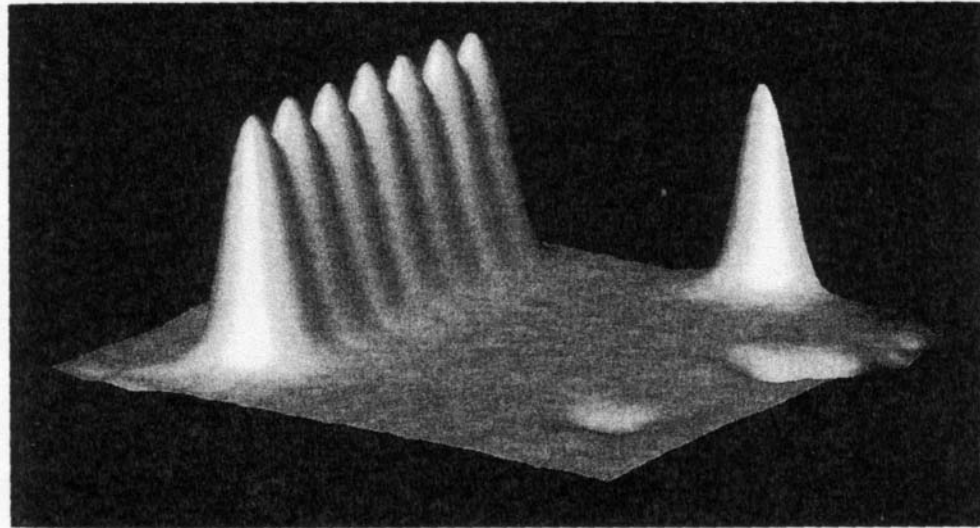
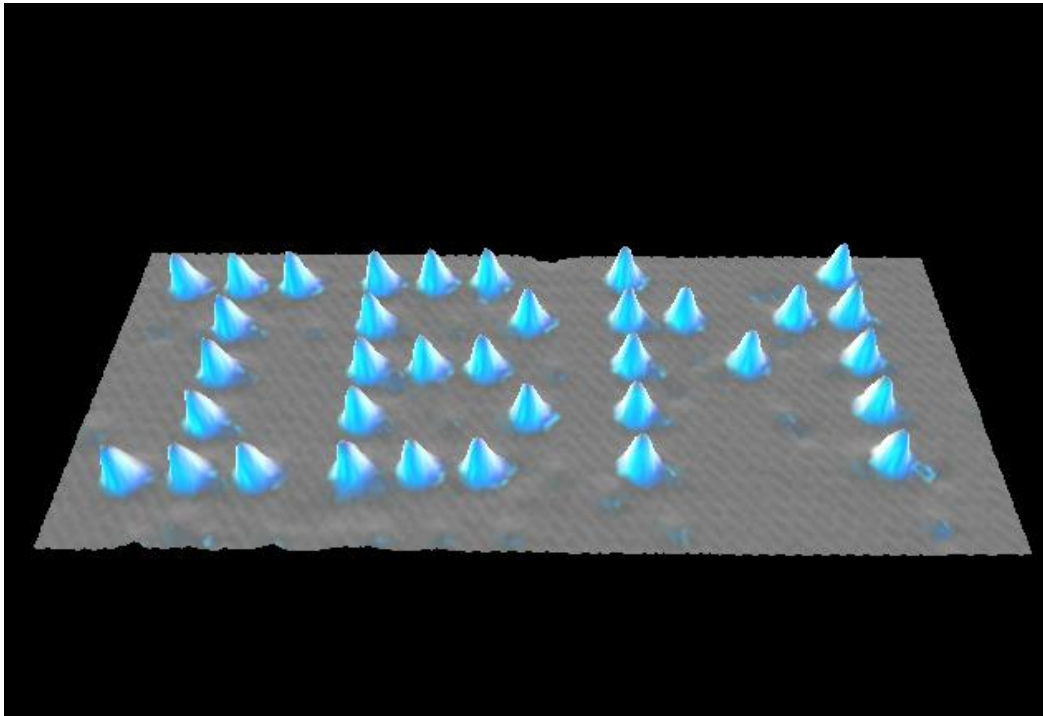


FIGURE 5. A row of seven xenon atoms constructed with the STM. The xenon atoms are spaced apart every other atom of the underlying nickel surface. The xenon atom cannot be packed together any tighter and remain in a single row. From building structures like this we learn about the strength of the xenon-xenon interaction relative to the strength of the in-plane interaction between the xenon atoms and the underlying nickel atoms.

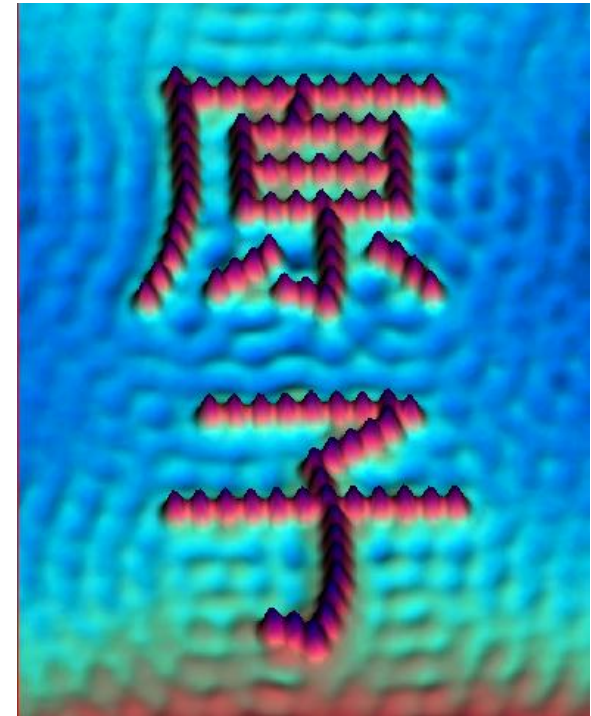
G. Timp, *Nanotechnology*, Chapter 11

# Nanograffiti

*Kanji for atom:*



**Xenon atoms on Nickel (110)**



**Fe atoms on Cu(111)**

Don Eigler, IBM Almaden, <http://www.almaden.ibm.com/vis/stm/atomo.html>